

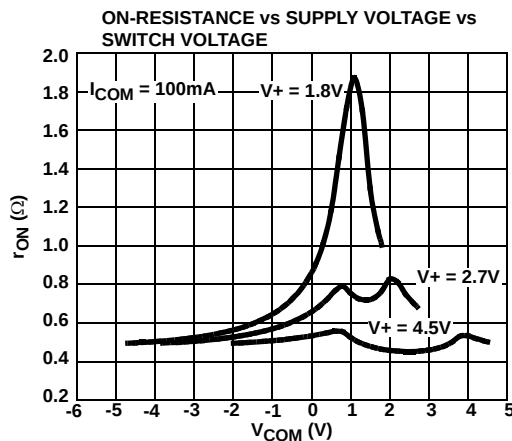
Negative Signal Swing, Sub-ohm, Dual SPST with Click and Pop Elimination Single Supply Switch

The Intersil ISL54063 and ISL54064 devices are a low ON-resistance, low voltage, bi-directional, dual single-pole/single-throw (SPST) analog switch. It is designed to operate from a single +1.8V to +6.5V supply and pass signals that swing down to 6.5V below the positive supply rail. Targeted applications include battery powered equipment that benefit from low r_{ON} (0.56Ω), low power consumption (20nA) and fast switching speeds ($t_{ON} = 55ns$, $t_{OFF} = 18ns$). The digital inputs are 1.8V logic-compatible up to a +3V supply. The ISL54063 and ISL54064 also features integrated circuitry to eliminate click and pop noise to an audio speaker. The ISL54063, ISL54064 are offered in a small form factor package, alleviating board space limitations. It is available in a tiny 10 Ld 1.8 x 1.4mm μ TQFN or 10 Ld 3mmx3mm TDFN package.

The ISL54063 is a committed dual single-pole/single-throw (SPST) that consist of two normally open (NO) switches with independent logic control. The ISL54064 is a committed dual single-pole/single-throw (SPST) that consist of two normally closed (NC) switches with independent logic control.

TABLE 1. FEATURES AT A GLANCE

	ISL54063	ISL54064
Number of Switches	2	2
SW	SPST NO	SPST NC
4.3V r_{ON}	0.65Ω	0.65Ω
4.3V t_{ON}/t_{OFF}	43ns/23ns	43ns/23ns
2.7V r_{ON}	0.9Ω	0.9Ω
2.7V t_{ON}/t_{OFF}	55ns/18ns	55ns/18ns
1.8V r_{ON}	1.8Ω	1.8Ω
1.8V t_{ON}/t_{OFF}	145ns/28ns	145ns/28ns
Packages	10 Ld μ TQFN, 10 Ld TDFN	



Features

- Pb-free (RoHS Compliant)
- Negative Signal Swing (Max 6.5V below $V+$)
- Audio Click and Pop Elimination Circuitry
- ON-Resistance (r_{ON})
 - $V+ = +4.5V$ 0.55Ω
 - $V+ = +4.3V$ 0.57Ω
 - $V+ = +2.7V$ 0.82Ω
 - $V+ = +1.8V$ 1.8Ω
- r_{ON} Matching Between Channels 10mΩ
- r_{ON} Flatness Across Signal Range 0.35Ω
- Low THD+N @ 32Ω Load 0.02%
- Single Supply Operation. +1.8V to +6.5V
- Low Power Consumption @ 3V (P_D) 24nW
- Fast Switching Action ($V+ = +4.3V$)
 - t_{ON} 43ns
 - t_{OFF} 23ns
- ESD HBM Rating >6kV
- Guaranteed Break-before-Make
- 1.8V Logic Compatible (+3V supply)
- Low $I+$ Current when V_{INH} is not at the $V+$ Rail
- Available in 10 Ld μ TQFN 1.8x1.4mm and 10 Ld 3x3mm TDFN

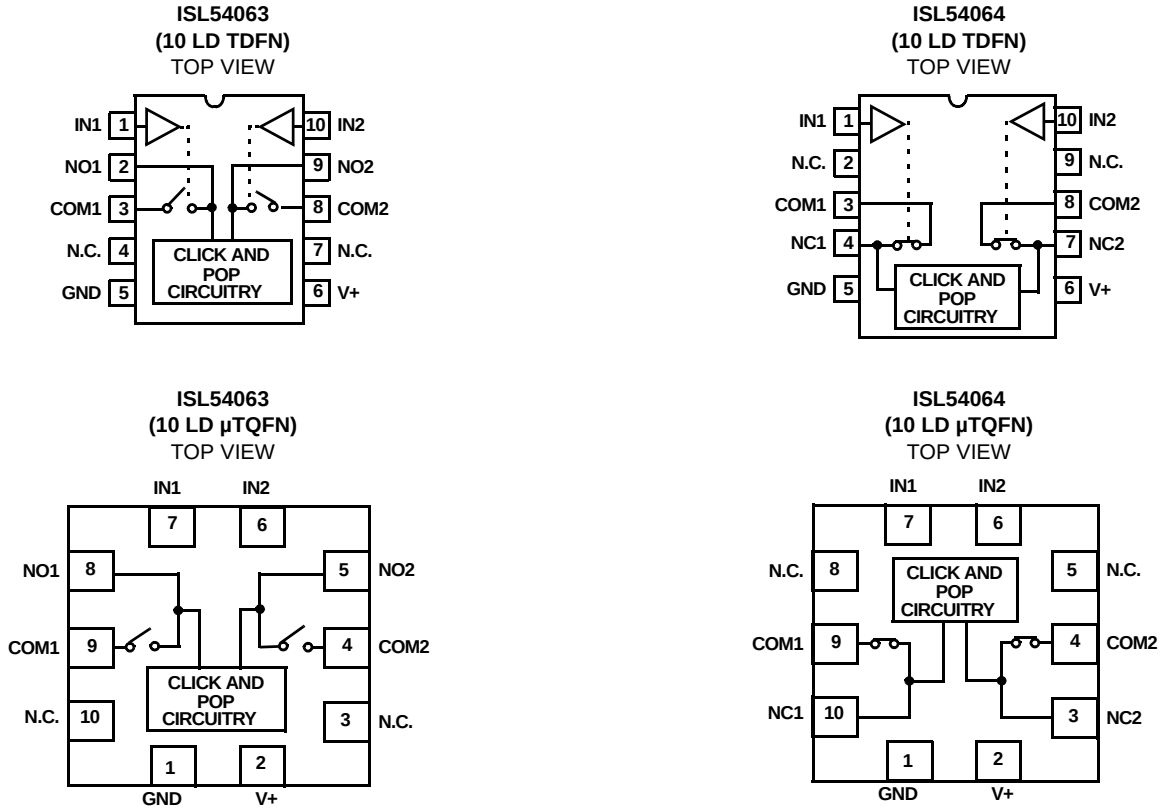
Applications

- Audio and Video Switching
- Battery powered, Handheld, and Portable Equipment
 - MP3 and Multimedia Players
 - Cellular/mobile Phones
 - Pagers
 - Laptops, Notebooks, Palmtops
- Portable Test and Measurement
- Medical Equipment

Related Literature

- Technical Brief TB363 "Guidelines for Handling and Processing Moisture Sensitive Surface Mount Devices (SMDs)"
- Application Note AN557 "Recommended Test Procedures for Analog Switches"

Pinouts (Note 1)



NOTE:

1. Switches Shown for INx = Logic "0".

Truth Table

INx	ISL54063 NOx to COMx	ISL54064 NCx to COMx
0	OFF	ON
1	ON	OFF

NOTE: Logic "0" $\leq 0.5V$. Logic "1" $\geq 1.4V$ with a 3V supply.

Pin Descriptions

PIN	FUNCTION
V+	IC Power Supply (+1.8V to +6.5V). Decouple V+ to ground by placing a 0.1μF capacitor at the V+ and GND supply lines as near as the IC as possible.
GND	Ground Connection
INx	Digital Control Input
COM	Analog Switch Common Pin
NOx	Analog Switch Normally Open Pin
NCx	Analog Switch Normally Closed Pin
N.C.	No Connect

Ordering Information

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL54063IRTZ (Note 3)	4063	-40 to +85	10 Ld 3x3 TDFN	L10.3x3A
ISL54063IRTZ-T (Notes 2, 3)	4063	-40 to +85	10 Ld 3x3 TDFN (Tape and Reel)	L10.3x3A
ISL54063IRUZ-T (Notes 2, 4)	T6	-40 to +85	10 Ld Thin μ TQFN (Tape and Reel)	L10.1.8x1.4A
ISL54064IRTZ (Note 3)	4064	-40 to +85	10 Ld 3x3 TDFN	L10.3x3A
ISL54064IRTZ-T (Notes 2, 3)	4064	-40 to +85	10 Ld 3x3 TDFN (Tape and Reel)	L10.3x3A
ISL54064IRUZ-T (Notes 2, 4)	T7	-40 to +85	10 Ld Thin μ TQFN (Tape and Reel)	L10.1.8x1.4A

NOTES:

- Please refer to TB347 for details on reel specifications.
- These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and NiPdAu plate - e4 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Absolute Maximum Ratings

V+ to GND	-0.5 to 7.0V
Input Voltages	
NOx, NCx (Note 5)	(V+ - 7V) to ((V+) + 0.5V)
INx (Note 5)	-0.5 to ((V+) + 0.5V)
Output Voltages	
COMx (Note 5)	(V+ - 7V) to ((V+) + 0.5V)
Continuous Current NOx, NCx, or COMx	±300mA
Peak Current NOx, NCx, or COMx (Pulsed 1ms, 10% Duty Cycle, Max)	±500mA
ESD Rating:	
Human Body Model	>6kV
Machine Model	>400V
Charged Device Model	>1.5kV

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
10 Ld 3x3 TDFN Package (Notes 6, 8)	55	18
10 Ld μ TQFN Package (Note 7)	155	N/A
Maximum Junction Temperature (Plastic Package)	+150°C	
Maximum Storage Temperature Range	-65°C to +150°C	
Pb-Free Reflow Profile	see link below http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

Operating Conditions

Temperature Range	-40°C to +85°C
Power Supply Range	+1.8V to +6.5V

AUTON: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- Signals on NC, NO, IN, or COM exceeding V+ or GND by the specified amount are clamped by internal diodes. Limit forward diode current to maximum current ratings.
- θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- For θ_{JC} , the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specifications - 5V Supply

Test Conditions: V+ = +4.5V to +5.5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V (Note 9), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
ANALOG SWITCH CHARACTERISTICS						
ON-Resistance, r_{ON}	$V+ = 4.5V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V+ - 6.5)$ to $V+$ (see Figure 4)	25	-	0.55	-	Ω
		Full	-	0.68	-	Ω
r_{ON} Matching Between Channels, Δr_{ON}	$V+ = 4.5V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} =$ Voltage at max r_{ON} , (Note 13)	25	-	15	-	m Ω
		Full	-	30	-	m Ω
r_{ON} Flatness, $R_{FLAT(ON)}$	$V+ = 4.5V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V+ - 6.5)$ to $V+$, (Note 12)	25	-	0.11	-	Ω
		Full	-	0.14	-	Ω
COM ON Leakage Current, $I_{COM(ON)}$	$V+ = 5V$, $V_{COM} = -1.5V, 5V$, V_{NO} or $V_{NC} =$ Float	25	-	49	-	nA
		Full	-	0.7	-	μA
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t_{ON}	$V+ = 4.5V$, V_{NO} or $V_{NC} = 3.0V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	35	-	ns
		Full	-	30	-	ns
Turn-OFF Time, t_{OFF}	$V+ = 4.5V$, V_{NO} or $V_{NC} = 3.0V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	10	-	ns
		Full	-	15	-	ns
Charge Injection, Q	$V_G = 0V$, $R_G = 0\Omega$, $C_L = 1.0nF$ (see Figure 2)	25	-	170	-	pC
OFF-Isolation	$R_L = 50\Omega$, $C_L = 5pF$, $f = 100kHz$, $V_{COM} = 1V_{RMS}$ (see Figure 3)	25	-	60	-	dB
Crosstalk (Channel-to-Channel)	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, $V_{COM} = 1V_{RMS}$ (see Figure 5)	25	-	-75	-	dB
Total Harmonic Distortion	$f = 20Hz$ to $20kHz$, $V_{COM} = 0.5V_{P-P}$, $R_L = 32\Omega$	25	-	0.02	-	%
-3dB Bandwidth	$V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$	25	-	60	-	MHz
NO x or NCx OFF Capacitance, C_{OFF}	$f = 1MHz$	25	-	36	-	pF
COMx ON Capacitance, $C_{COM(ON)}$	$f = 1MHz$ (See Figure 6)	25	-	88	-	pF

Electrical Specifications - 5V Supply Test Conditions: $V_+ = +4.5V$ to $+5.5V$, $GND = 0V$, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$ (Note 9), Unless Otherwise Specified. **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
POWER SUPPLY CHARACTERISTICS						
Positive Supply Current, I+	V+ = 5.5V, VIN = 0V or V+	25	-	0.02	0.1	μA
		Full	-	2.5	-	μA
DIGITAL INPUT CHARACTERISTICS						
Input Voltage Low, VINL		Full	-	-	0.8	V
Input Voltage High, VINH		Full	2.4	-	-	V
Input Current, IINH, IINL	V+ = 5.5V, VIN = 0V or V+	25	-0.1	-	0.1	μA
		Full	-	0.89	-	μA

Electrical Specifications - 4.3V Supply Test Conditions: $V_+ = +3.9V$ to $+4.5V$, $GND = 0V$, $V_{INH} = 1.6V$, $V_{INL} = 0.5V$ (Note 9), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
ANALOG SWITCH CHARACTERISTICS						
ON-Resistance, r_{ON}	$V_+ = 4.3V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V_+ - 6.5V)$ to V_+ , (See Figure 4)	25	-	0.57	-	Ω
		Full	-	0.68	-	Ω
r_{ON} Matching Between Channels, Δr_{ON}	$V_+ = 4.3V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} =$ Voltage at max r_{ON} , (Note 13)	25	-	15	-	m Ω
		Full	-	30	-	m Ω
r_{ON} Flatness, $R_{FLAT(ON)}$	$V_+ = 4.3V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V_+ - 6.5V)$ to V_+ , (Note 12)	25	-	0.1	-	Ω
		Full	-	0.14	-	Ω
COM ON Leakage Current, $I_{COM(ON)}$	$V_+ = 4.3V$, $V_{COM} = -1.2V$, $4.3V$, V_{NO} or $V_{NC} =$ Float	25	-0.1	-	0.1	μA
		Full	-	1.1	-	μA
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t_{ON}	$V_+ = 3.9V$, V_{NO} or $V_{NC} = 3.0V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	43	-	ns
		Full	-	50	-	ns
Turn-OFF Time, t_{OFF}	$V_+ = 3.9V$, V_{NO} or $V_{NC} = 3.0V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	23.1	-	ns
		Full	-	23.2	-	ns
Charge Injection, Q	$C_L = 1.0nF$, $V_G = 0V$, $R_G = 0\Omega$ (see Figure 2)	25	-	200	-	pC
OFF-Isolation	$R_L = 50\Omega$, $C_L = 5pF$, $f = 100kHz$, $V_{COM} = 1V_{RMS}$ (see Figure 3)	25	-	60	-	dB
Crosstalk (Channel-to-Channel)	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, $V_{COM} = 1V_{RMS}$ (see Figure 5)	25	-	-75	-	dB
Total Harmonic Distortion	$f = 20Hz$ to $20kHz$, $V_{COM} = 2V_{P-P}$, $R_L = 32\Omega$	25	-	0.04	-	%
-3dB Bandwidth	$V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$	25	-	60	-	MHz
NOx or NCx OFF Capacitance, C_{OFF}	$f = 1MHz$	25	-	36	-	pF
COMx ON Capacitance, $C_{COM(ON)}$	$f = 1MHz$ (see Figure 6)	25	-	88	-	pF
POWER SUPPLY CHARACTERISTICS						
Positive Supply Current, I_+	$V_+ = +4.5V$, $V_{IN} = 0V$ or V_+	25	-	0.003	0.1	μA
		Full	-	2.6	-	μA
Positive Supply Current, I_+	$V_+ = +4.2V$, $V_{IN} = 2.85V$	25	-	0.89	12	μA

Electrical Specifications - 4.3V Supply

Test Conditions: $V_+ = +3.9V$ to $+4.5V$, $GND = 0V$, $V_{INH} = 1.6V$, $V_{INL} = 0.5V$ (Note 9), Unless Otherwise Specified. (Continued)

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
DIGITAL INPUT CHARACTERISTICS						
Input Voltage Low, V_{INL}		Full	-	-	0.5	V
Input Voltage High, V_{INH}		Full	1.6	-	-	V
Input Current, I_{INH} , I_{INL}	$V_+ = 4.5V$, $V_{IN} = 0V$ or V_+	25	-0.5	-	0.5	μA
		Full	-	0.5	-	μA

Electrical Specifications - 3V Supply

Test Conditions: $V_+ = +2.7V$ to $+3.3V$, $GND = 0V$, $V_{INH} = 1.4V$, $V_{INL} = 0.5V$ (Note 9), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
ANALOG SWITCH CHARACTERISTICS						
ON-Resistance, r_{ON}	$V_+ = 2.7V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V_+ - 6.5V)$ to V_+ (see Figure 4)	25	-	0.82	-	Ω
		Full	-	0.94	-	Ω
r_{ON} Matching Between Channels, Δr_{ON}	$V_+ = 2.7V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} =$ Voltage at max r_{ON} , (Note 13)	25	-	10	-	$m\Omega$
		Full	-	30	-	$m\Omega$
r_{ON} Flatness, $R_{FLAT(ON)}$	$V_+ = 2.7V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V_+ - 6.5V)$ to V_+ , (Notes 12, 14)	25	-	0.35	0.5	Ω
		Full	-	0.4	0.55	Ω
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t_{ON}	$V_+ = 2.7V$, V_{NO} or $V_{NC} = 1.5V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	50	-	ns
		Full	-	60	-	ns
Turn-OFF Time, t_{OFF}	$V_+ = 2.7V$, V_{NO} or $V_{NC} = 1.5V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	27	-	ns
		Full	-	35	-	ns
Charge Injection, Q	$C_L = 1.0nF$, $V_G = 0V$, $R_G = 0\Omega$ (see Figure 2)	25	-	94	-	pC
OFF-Isolation	$R_L = 50\Omega$, $C_L = 5pF$, $f = 100kHz$, $V_{COM} = 1V_{RMS}$ (see Figure 3)	25	-	60	-	dB
Crosstalk (Channel-to-Channel)	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, $V_{COM} = 1V_{RMS}$ (see Figure 5)	25	-	-75	-	dB
Total Harmonic Distortion	$f = 20Hz$ to $20kHz$, $V_{COM} = 0.5V_{P-P}$, $R_L = 32\Omega$	25	-	0.04	-	%
-3dB Bandwidth	$V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$	25	-	60	-	MHz
NOx or NCx OFF Capacitance, C_{OFF}	$f = 1MHz$	25	-	36	-	pF
COMx ON Capacitance, $C_{COM(ON)}$	$f = 1MHz$ (see Figure 6)	25	-	88	-	pF
DIGITAL INPUT CHARACTERISTICS						
Input Voltage Low, V_{INL}		25	-	-	0.5	V
Input Voltage High, V_{INH}		25	1.4	-	-	V
Input Current, I_{INH} , I_{INL}	$V_+ = 3.3V$, $V_{IN} = 0V$ or V_+	25	-0.5	-	0.5	μA
		Full	-	0.4	-	μA

Electrical Specifications - 1.8V Supply

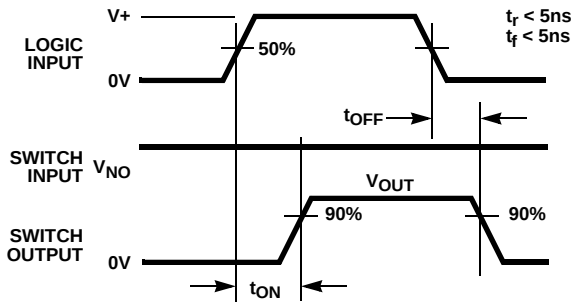
Test Conditions: $V+ = +1.8V$, $GND = 0V$, $V_{INH} = 1.0V$, $V_{INL} = 0.4V$ (Note 9), Unless Otherwise Specified.

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN (Notes 10, 11)	TYP	MAX (Notes 10, 11)	UNITS
ANALOG SWITCH CHARACTERISTICS						
ON-Resistance, r_{ON}	$V+ = 1.8V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V+ -6.5V)$ to $V+$ (see Figure 4)	25	-	1.87	-	Ω
		Full	-	1.97	-	Ω
r_{ON} Matching Between Channels, Δr_{ON}	$V+ = 1.8V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} =$ Voltage at max r_{ON} , (Note 13)	25	-	16	-	$m\Omega$
		Full	-	30	-	$m\Omega$
r_{ON} Flatness, $R_{FLAT(ON)}$	$V+ = 1.8V$, $I_{COM} = 100mA$, V_{NO} or $V_{NC} = (V+ -6.5V)$ to $V+$, (Note 12)	25	-	1.34	-	Ω
		Full	-	1.43	-	Ω
DYNAMIC CHARACTERISTICS						
Turn-ON Time, t_{ON}	$V+ = 1.8V$, V_{NO} or $V_{NC} = 1.8V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	145	-	ns
		Full	-	150	-	ns
Turn-OFF Time, t_{OFF}	$V+ = 1.8V$, V_{NO} or $V_{NC} = 1.8V$, $R_L = 50\Omega$, $C_L = 35pF$ (see Figure 1)	25	-	20	-	ns
		Full	-	22	-	ns
Charge Injection, Q	$C_L = 1.0nF$, $V_G = 0V$, $R_G = 0\Omega$ (see Figure 2)	25	-	40	-	pC
-3dB Bandwidth	$V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$	25	-	60	-	MHz
NOx or NCx OFF Capacitance, C_{OFF}	$f = 1MHz$ (see Figure 6)	25	-	36	-	pF
COMx ON Capacitance, $C_{COM(ON)}$	$f = 1MHz$ (see Figure 6)	25	-	88	-	pF
DIGITAL INPUT CHARACTERISTICS						
Input Voltage Low, V_{INL}		25	-	-	0.4	V
Input Voltage High, V_{INH}		25	1.0	-	-	V
Input Current, I_{INH} , I_{INL}	$V+ = 2.0V$, $V_{IN} = 0V$ or $V+$	25	-0.5	-	0.5	μA
Input Current, I_{INH} , I_{INL}	$V+ = 2.0V$, $V_{IN} = 0V$ or $V+$	Full	-	0.38	-	μA

NOTES:

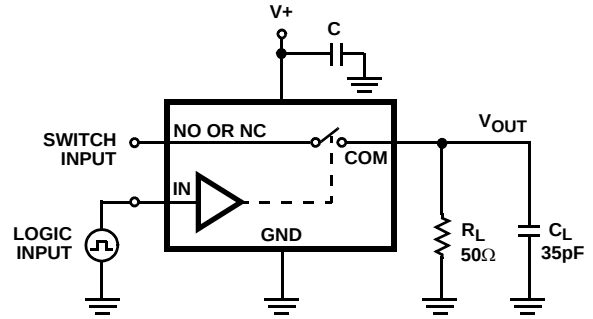
9. V_{IN} = input voltage to perform proper function.
10. The algebraic convention, whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
11. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
12. Flatness is defined as the difference between maximum and minimum value of ON-resistance over the specified analog signal range.
13. r_{ON} matching between channels is calculated by subtracting the channel with the highest max r_{ON} value from the channel with lowest max r_{ON} value, between NC1 and NC2 or between NO1 and NO2.
14. Limits established by characterization and are not production tested.

Test Circuits and Waveforms



Logic input waveform is inverted for switches that have the opposite logic sense.

FIGURE 1A. MEASUREMENT POINTS



Repeat test for all switches. C_L includes fixture and stray capacitance.

$$V_{OUT} = V_{(NO \text{ or } NC)} \frac{R_L}{R_L + r_{ON}}$$

FIGURE 1B. TEST CIRCUIT

FIGURE 1. SWITCHING TIMES

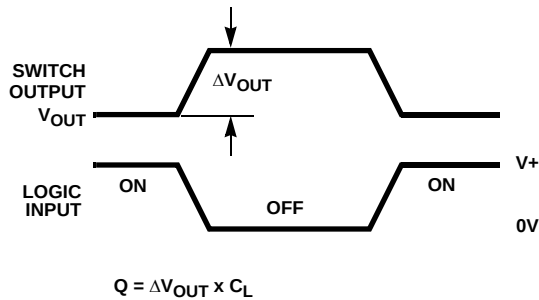
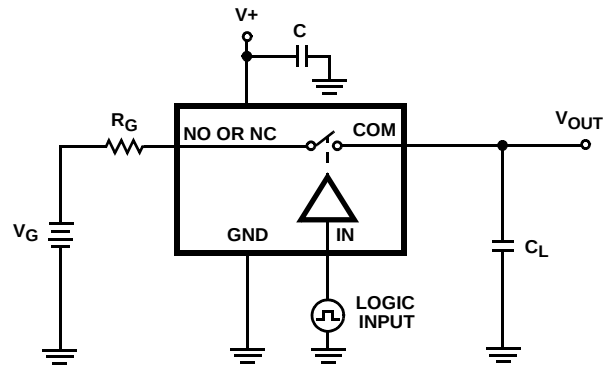


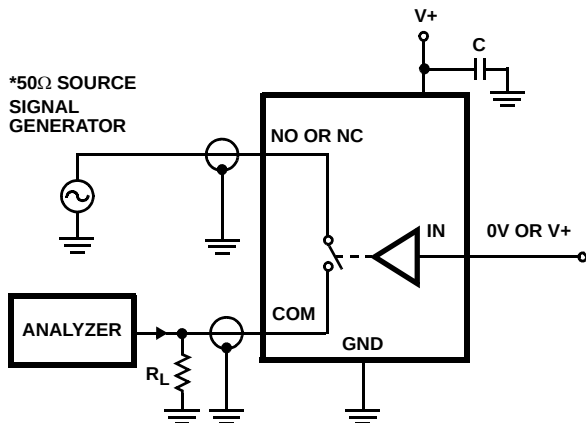
FIGURE 2A. MEASUREMENT POINTS



Repeat test for all switches.

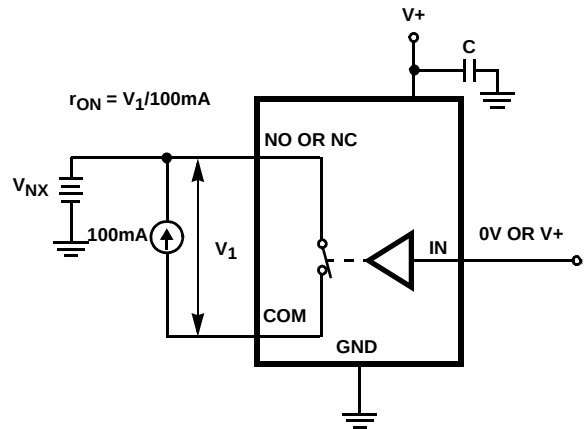
FIGURE 2B. TEST CIRCUIT

FIGURE 2. CHARGE INJECTION



Signal direction through switch is reversed, worst case values are recorded. Repeat test for all switches.

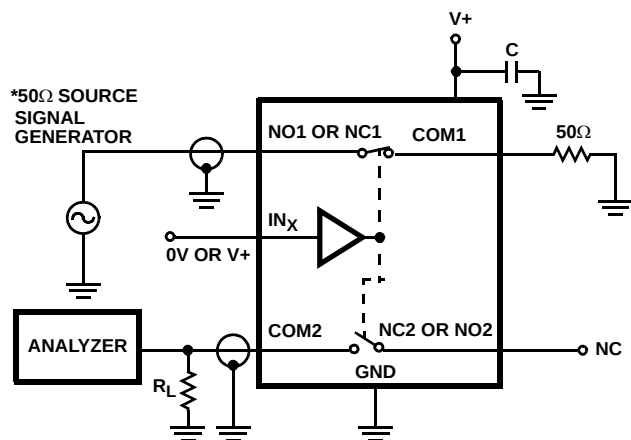
FIGURE 3. OFF-ISOLATION TEST CIRCUIT



Repeat test for all switches.

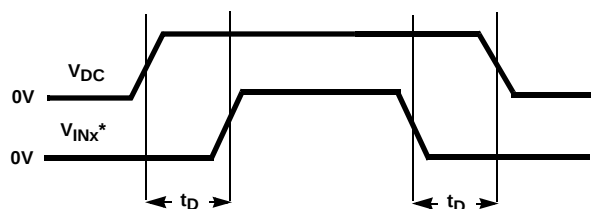
FIGURE 4. r_{ON} TEST CIRCUIT

Test Circuits and Waveforms (Continued)



Signal direction through switch is reversed, worst case values are recorded. Repeat test for all switches.

FIGURE 5. CROSSTALK TEST CIRCUIT



* V_{INx} waveform for Click and Pop Elimination on NOx terminal. For Click and Pop Elimination on NCx terminal invert V_{INx} .

$t_D = 200\text{ms}$ measured at 50% points.

FIGURE 7A. CLICK AND POP WAVEFORM

FIGURE 7. CLICK AND POP ELIMINATION

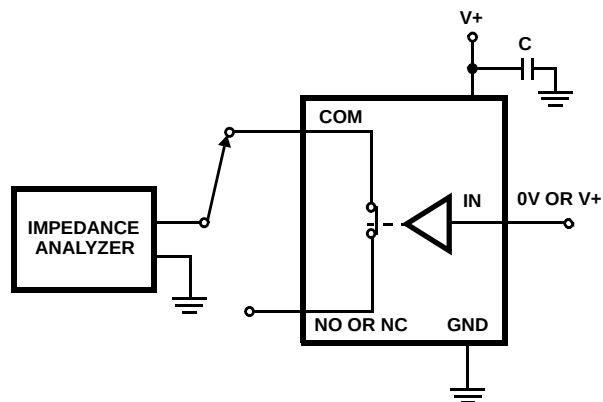


FIGURE 6. CAPACITANCE TEST CIRCUIT

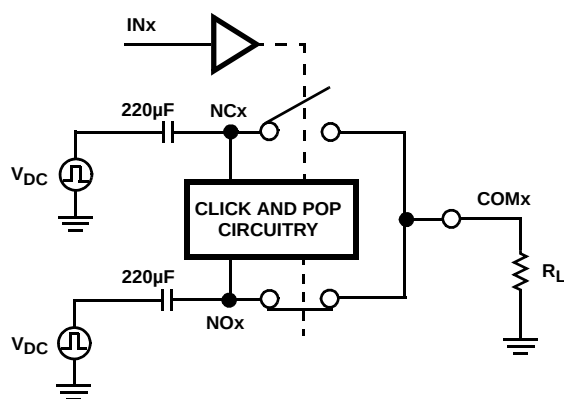


FIGURE 7B. CLICK AND POP TEST CIRCUIT

Detailed Description

The ISL54063 and ISL54064 are bidirectional, dual single pole-single throw (SPST) analog switches that offers precise switching from a single 1.8V to 6.5V supply with low ON-resistance (0.83Ω), high speed operation ($t_{ON} = 55\text{ns}$, $t_{OFF} = 18\text{ns}$) and negative signal swing capability. The device is especially well suited for portable battery powered equipment due to its low operating supply voltage (1.8V), low power consumption (20nA), and a tiny 1.8mmx1.4mm μTQFN package or a 3mmx3mm TDFN package. The low ON-resistance and r_{ON} flatness provide very low insertion loss and signal distortion for applications that require signal switching with minimal interference by the switch.

The ISL54063 is a normally open (NO) SPST analog switch. The ISL54064 is a normally closed (NC) SPST analog switch.

Supply Sequencing and Overvoltage Protection

With any CMOS device, proper power supply sequencing is required to protect the device from excessive input currents

which might permanently damage the IC. The ISL54063 and ISL54064 contains ESD protection diodes on each pin of the IC (see Figure 8). These diodes connect to either a +Ring or -Ring for ESD protection. To prevent forward biasing the ESD diodes to the +Ring, $V+$ must be applied before any input signals, and the input signal voltages must remain between recommended operating range.

If these conditions cannot be guaranteed, then precautions must be implemented to prohibit the current and voltage at the logic pin and signal pins from exceeding the maximum ratings of the switch. The following two methods can be used to provided additional protection to limit the current in the event that the voltage at a logic pin or switch terminal goes above the $V+$ rail.

Logic inputs can be protected by adding a $1\text{k}\Omega$ resistor in series with the logic input (see Figure 8). The resistor limits the input current below the threshold that produces permanent damage.

Typical Performance Curves $T_A = +25^\circ\text{C}$, Unless Otherwise Specified

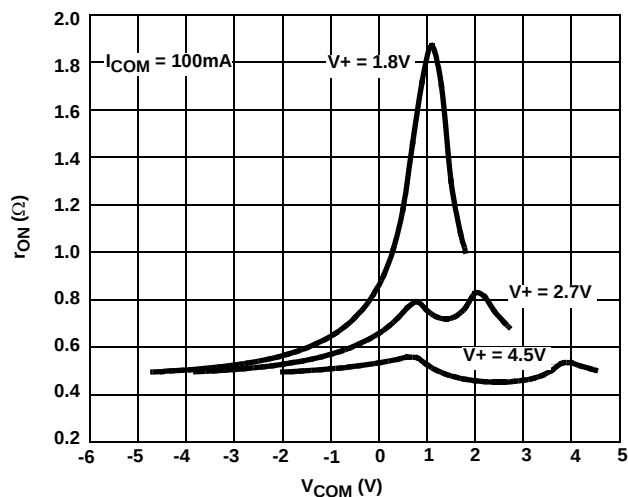


FIGURE 9. ON-RESISTANCE vs SUPPLY VOLTAGE vs SWITCH VOLTAGE

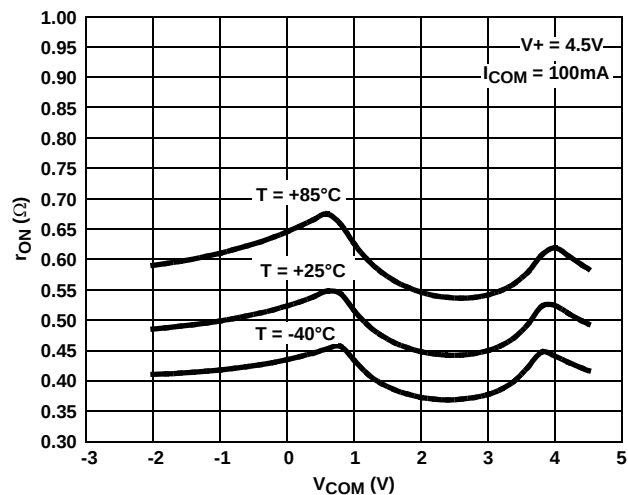


FIGURE 10. ON-RESISTANCE vs SWITCH VOLTAGE

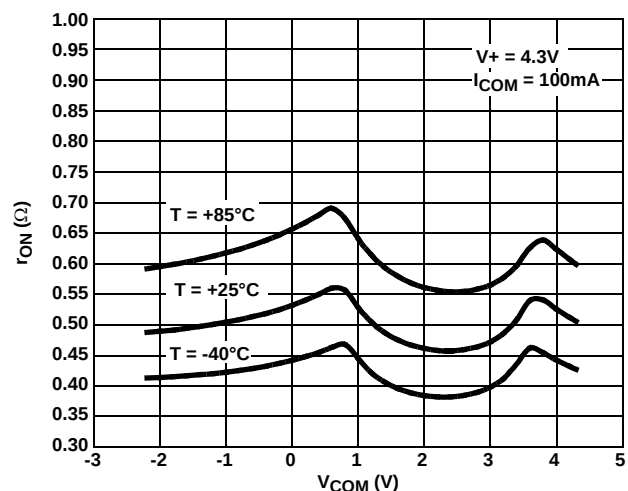


FIGURE 11. ON-RESISTANCE vs SWITCH VOLTAGE

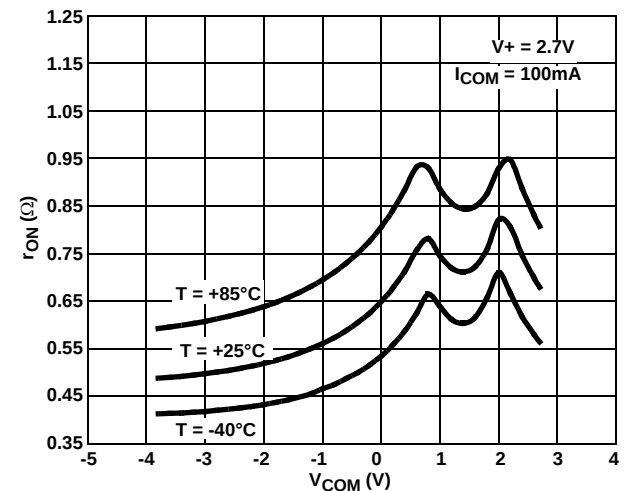


FIGURE 12. ON-RESISTANCE vs SWITCH VOLTAGE

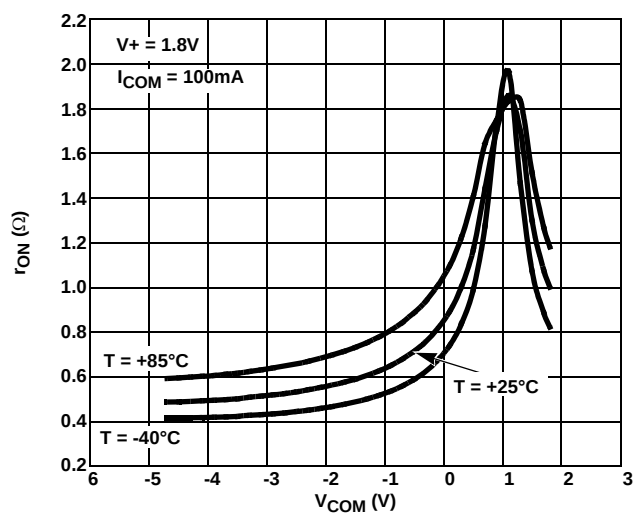


FIGURE 13. ON-RESISTANCE vs SWITCH VOLTAGE

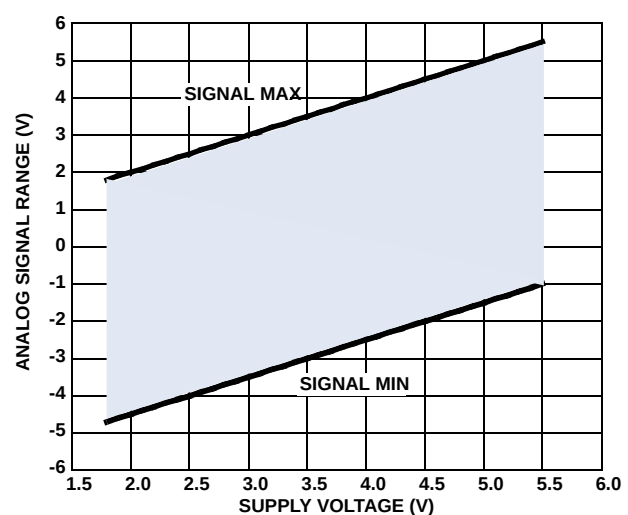


FIGURE 14. ANALOG SIGNAL RANGE vs SUPPLY VOLTAGE

Typical Performance Curves $T_A = +25^\circ\text{C}$, Unless Otherwise Specified (Continued)

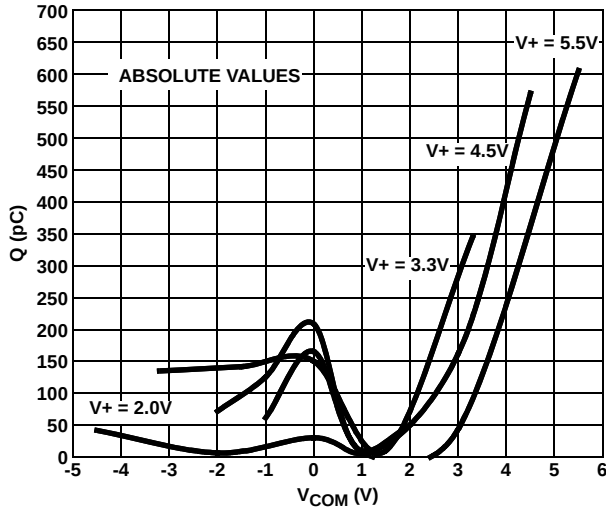


FIGURE 15. CHARGE INJECTION vs SWITCH VOLTAGE

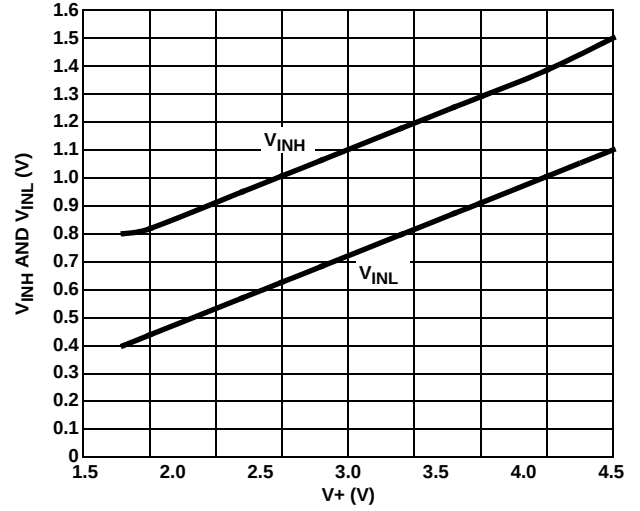


FIGURE 16. DIGITAL SWITCHING POINT vs SUPPLY VOLTAGE

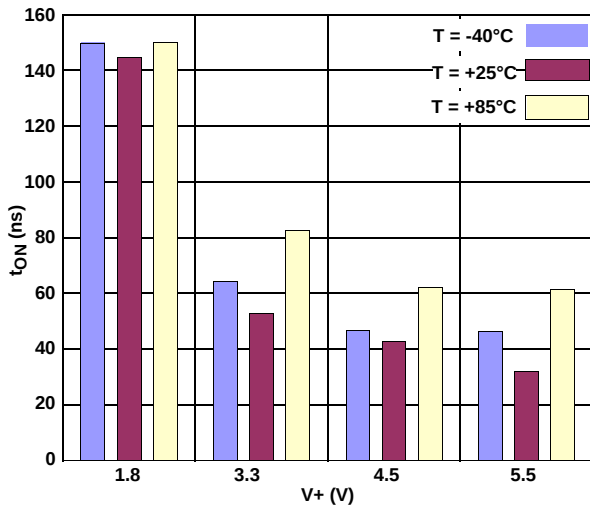


FIGURE 17. TURN - ON TIME vs SUPPLY VOLTAGE

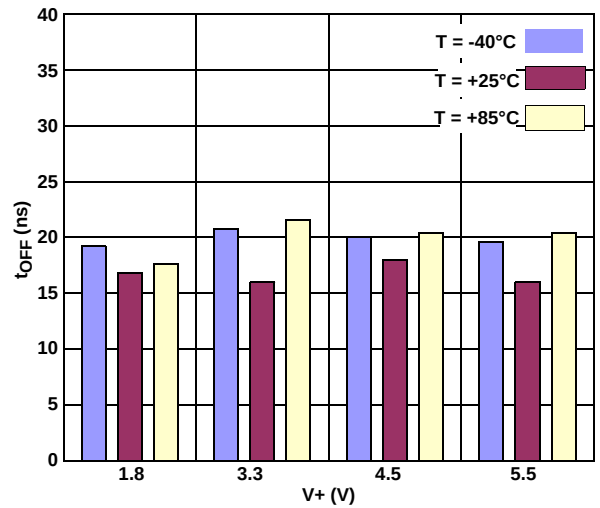


FIGURE 18. TURN - OFF TIME vs SUPPLY VOLTAGE

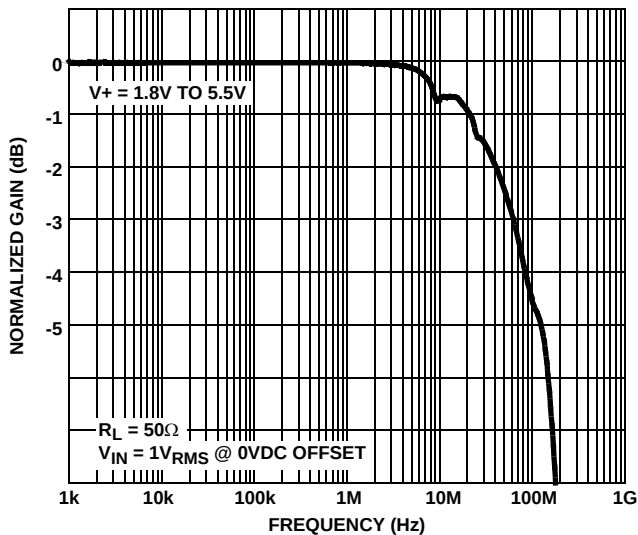


FIGURE 19. FREQUENCY RESPONSE

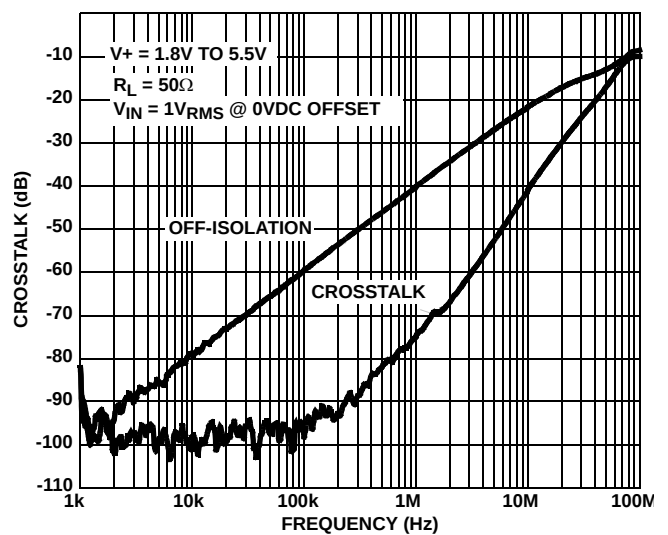


FIGURE 20. CROSSTALK AND OFF-ISOLATION

Typical Performance Curves $T_A = +25^\circ\text{C}$, Unless Otherwise Specified (Continued)

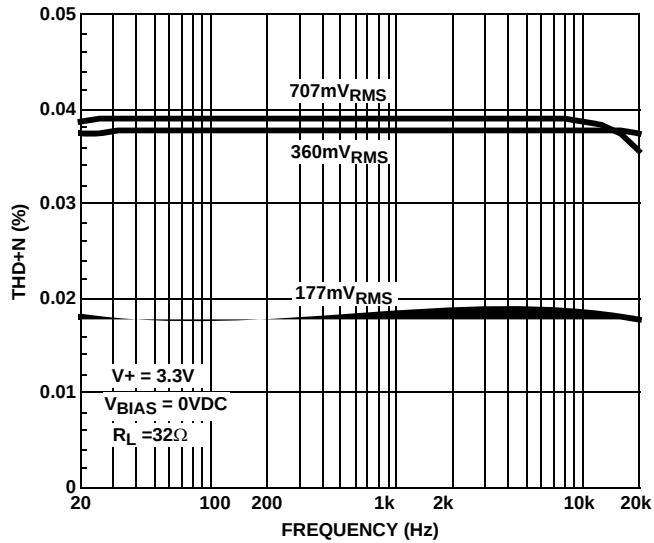


FIGURE 21. TOTAL HARMONIC DISTORTION vs FREQUENCY

Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

GND (DFN Paddle Connection: Tie to GND or Float)

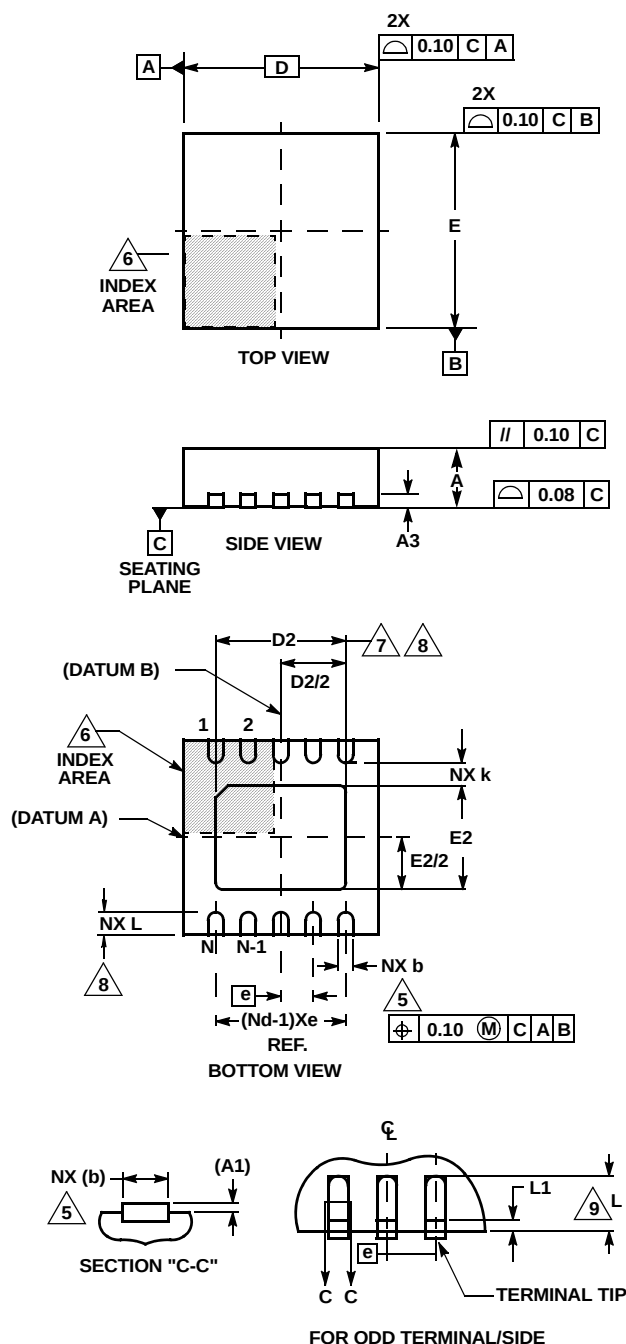
TRANSISTOR COUNT:

432

PROCESS:

Submicron CMOS

Thin Dual Flat No-Lead Plastic Package (TDFN)



L10.3x3A

10 LEAD THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE

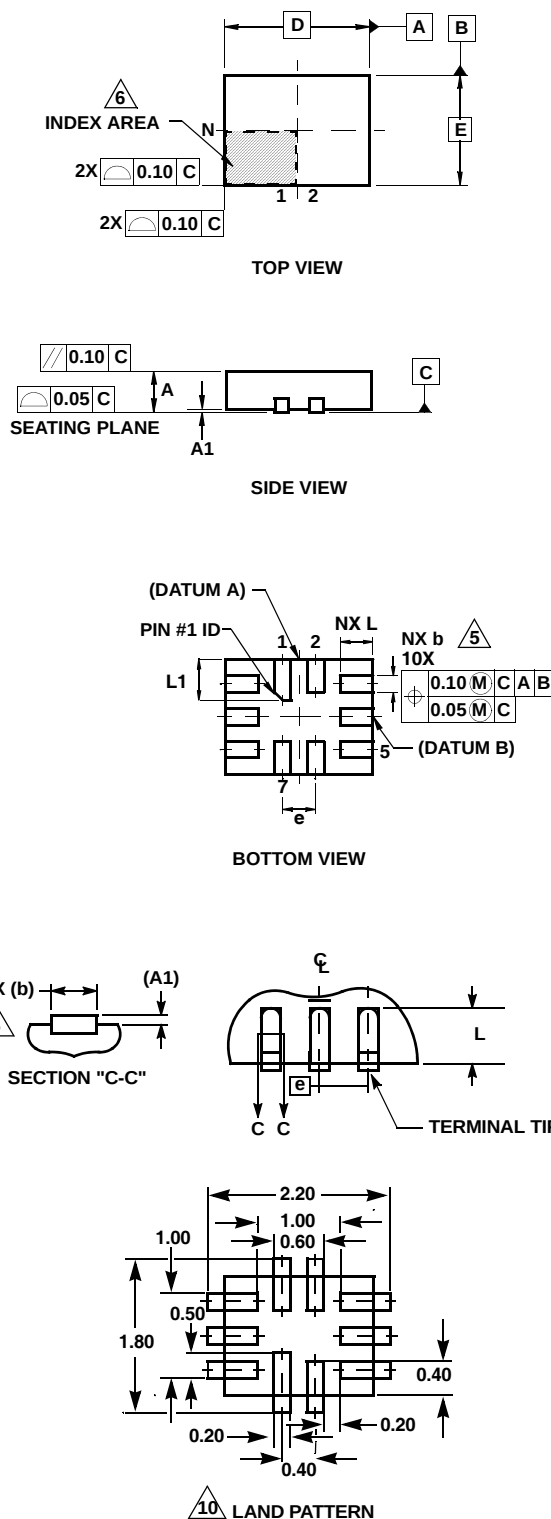
SYMBOL	MILLIMETERS			NOTES
	MIN	NOMINAL	MAX	
A	0.70	0.75	0.80	-
A1	-	-	0.05	-
A3	0.20 REF			-
b	0.20	0.25	0.30	5, 8
D	2.95	3.0	3.05	-
D2	2.25	2.30	2.35	7, 8
E	2.95	3.0	3.05	-
E2	1.45	1.50	1.55	7, 8
e	0.50 BSC			-
k	0.25	-	-	-
L	0.25	0.30	0.35	8
N	10			2
Nd	5			3

Rev. 3 3/06

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
2. N is the number of terminals.
3. Nd refers to the number of terminals on D.
4. All dimensions are in millimeters. Angles are in degrees.
5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.
8. Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.
9. Compliant to JEDEC MO-229-WEED-3 except for D2 dimensions.

Ultra Thin Quad Flat No-Lead Plastic Package (UTQFN)



L10.1.8x1.4A

10 LEAD ULTRA THIN QUAD FLAT NO-LEAD PLASTIC PACKAGE

SYMBOL	MILLIMETERS			NOTES
	MIN	NOMINAL	MAX	
A	0.45	0.50	0.55	-
A1	-	-	0.05	-
A3	0.127 REF			-
b	0.15	0.20	0.25	5
D	1.75	1.80	1.85	-
E	1.35	1.40	1.45	-
e	0.40 BSC			-
L	0.35	0.40	0.45	-
L1	0.45	0.50	0.55	-
N	10			2
Nd	2			3
Ne	3			3
θ	0	-	12	4

Rev. 3 6/06

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
2. N is the number of terminals.
3. Nd and Ne refer to the number of terminals on D and E side, respectively.
4. All dimensions are in millimeters. Angles are in degrees.
5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
7. Maximum package warpage is 0.05mm.
8. Maximum allowable burrs is 0.076mm in all directions.
9. JEDEC Reference MO-255.
10. For additional information, to assist with the PCB Land Pattern Design effort, see Intersil Technical Brief TB389.

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Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

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